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Description

The SLVU2.8-4 is designed to protect low voltage, CMOS semiconductors from transients caused by electrostatic discharge (ESD), cable discharge events (CDE), lightning and other induced voltage surges. Low capacitance compensation diode is integrated into the TVS to lower the typical capacitance to 1pf per line. The SLVU2.8-4 complies with the IEC 61000-4-2 (ESD) standard with ±15kV air and ±8kV contact discharge. The SLVU2.8-4 is assembled into a 8-pin lead-free SO-8 package, The combination of low leakage, signal integrity and flow through design makes the SLVU2.8-4 an ideal application such as 10/100/1000 Ethernet.

Features

- 400W peak pulse power (8/20µs)
- Protects two line pairs (four lines)
- Ultra low leakage: nA level
- Low operating voltage: 2.8V
- Very low capacitance: 1.0pF
- Ultra low clamping voltage
- JEDEC SO-8 package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: ±15kV
 - Contact discharge: ±8kV
 - IEC61000-4-5 (Lightning) 24A (8/20μs)
- RoHS Compliant

Mechanical Characteristics

- Package: SO-8
- Lead Finish: Matte Tin
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

- Base Station
- Analog Inputs
- Switch Systems
- 10/100/1000 Ethernet
- WAN/LAN Equipment
- Desktops, Servers, and Notebooks
- Low Voltage Interfaces



SOP-8



Circuit diagram



Ordering Information

Part Number	Packaging	Reel Size
SLVU2.8-4	2500/Tape & Reel	13 inch

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	Ppk	400	W	
Peak Pulse Current (8/20µs)	IPP	24	А	
ESD per IEC 61000-4-2 (Air)	VESD	±15	kV	
ESD per IEC 61000-4-2 (Contact)	VLOD	±8		
Operating Temperature Range	TJ	−55 to +125	°C	
Storage Temperature Range	Tstg	−55 to +150	°C	

Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Мах	Unit	Test Condition
Reverse Working Voltage	VRWM			2.8	V	
Breakdown Voltage	Vbr	3.0			V	Ιτ = 2μΑ
	Vsb	2.8			V	ISB= 50mA
Reverse Leakage Current	I _R		0.001	1	μA	VRWM = 2.8V
Clamping Voltage	Vc		6		V	IPP = 1A (8 x 20µs pulse)
Clamping Voltage	Vc		10		V	IPP = 10A (8 x 20µs pulse)
Clamping Voltage	Vc		16	20	V	IPP = 24A (8 x 20µs pulse)
Junction Capacitance	CJ		1	2	pF	VR = 0V, f = 1MHz

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SLVU2.8-4



Typical Performance Characteristics (T_A=25°C unless otherwise Specified)

Junction Capacitance vs. Reverse Voltage



Clamping Voltage vs. Peak Pulse Current



8 X 20µs Pulse Waveform



M 10.0ns Ch1 J

Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

8 kV Contact per IEC61000-4-2

981

i E

Ghi 10.0 V

Typical Application

The SLVU2.8-4 is designed such that the data lines are routed through the device. The first line pair enters at pins 1 and 2 and exit at pins 8 and 7 respectively. The second line pair enters at pins 3 and 4 and exits at pins 6 and 5. The traces must be connected at the bottom of the device as shown.



Low capacitance protection of two differential line pairs

SLVU2.8-4 on Ethernet Application

